PXIe-5820 Specifications

2023-08-04

Contents

PXIe-5820 Specifications

Definitions

Warranted specifications describe the performance of a model under stated operating conditions and are covered by the model warranty.

Characteristics describe values that are relevant to the use of the model under stated operating conditions but are not covered by the model warranty.

- **Typical** specifications describe the performance met by a majority of models.
- **Typical-95** specifications describe the performance met by 95% (≈2σ) of models with a 95% confidence.
- **Nominal** specifications describe an attribute that is based on design, conformance testing, or supplemental testing.

Specifications are **Warranted** unless otherwise noted.

Conditions

Warranted specifications are valid under the following conditions unless otherwise noted.

- Over ambient temperature range of 0 °C to 45 °C.
- 30 minutes warm-up time.
- Calibration cycle is maintained.
- Chassis fan speed is set to High. In addition, NI recommends using slot blockers and EMC filler panels in empty module slots to minimize temperature drift.
- Calibration IP is used properly during the creation of custom FPGA bitfiles.

Typical specifications do not include measurement uncertainty and are measured immediately after a device self-calibration is performed.

Unless otherwise noted, specifications assume the PXIe-5820 is configured in the following default mode of operation:

- I/Q IN voltage range: 2.0 V_{pk-pk} differential
- I/Q IN common-mode voltage: 0 V
- I/Q OUT voltage range: 1.0 V_{pk-pk} differential
- I/Q OUT common-mode voltage: 0 V
- I/Q OUT load impedance: 100 Ω differential

Note Within the specifications, **self-calibration °C** refers to the recorded device temperature of the last successful self-calibration. You can read the self-calibration temperature from the device using the appropriate software functions.

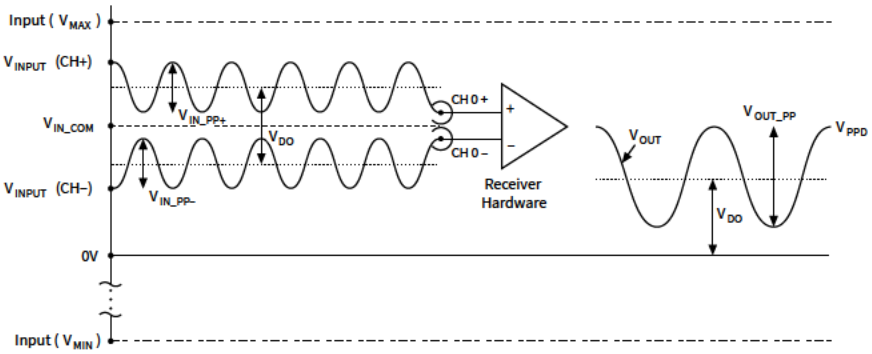
Differential Operation

The I/Q inputs and outputs of the PXIe-5820 support differential operation. This section explains some of the fundamental analog signal processing that occurs in the first stages of the I/Q receiver.

A differential signal system has a positive component (V_{INPUT}(CH+)) and a negative component (V_{INPUT}(CH-)). The differential signal can have a common-mode offset (V_{IN_COM}) shared by both V_{INPUT}(CH+) and V_{INPUT}(CH-). The differential input signal is superimposed on the common-mode offset. The input circuitry rejects the input common-mode offset signal.

In a differential system, any noise present on both V_{INPUT}(CH+) and V_{INPUT}(CH-) gets rejected. Differential systems also double the dynamic range compared to a single-ended system with the same voltage swing. The following figure illustrates the key concepts of differential offset and common-mode offset associated with a differential system.

Figure 1. Definition of Common-Mode Offset and Differential Offset



where

- V_{IN_PP+} represents the peak-to-peak amplitude of the positive AC input signal
- V_{IN_PP-} represents the peak-to-peak amplitude of the negative AC input signal
- V_{DO} represents the differential offset voltage
- V_{IN_COM} represents the common-mode offset voltage
- V_{OUT_PP} represents the peak-to-peak amplitude of the output signal

In the previous figure, the input common-mode voltage is not present after the first stage of the receiver system. The signal remaining at the output of the receiver circuitry is the signal of interest.

Note The differential signal can have an offset between V_{INPUT}(CH+) and V_{INPUT}(CH-). This is known as the **differential offset** and is retained by the receiver circuitry.

In an I/Q analyzer, a differential offset can occur because of LO leakage or harmonics. In the case of I/Q generation, a differential offset can cause spurs and magnitude error.

In a phase-balanced differential system, the peak-to-peak amplitude of the positive AC input signal (V_{IN_PP+}) is equal to the peak-to-peak amplitude of the negative AC input signal (V_{IN_PP-}). The AC peak-to-peak amplitude of the output signal is the sum

of V_{IN_PP+} and V_{IN_PP-}. A more general definition for the output voltage regardless of phase is the difference between V_{IN_PP+} and V_{IN_PP-} described by the following equation:

$V_{OUT} = (V_{INPUT}(CH+)) - (V_{INPUT}(CH-))$

The common-mode offset, which represents the rejected component common to both signals, is described by the following equation:

$V_{IN\_COM} = [(V_{INPUT}(CH+)) + (V_{INPUT}(CH-))]/2$

Frequency

Complex I/Q equalized bandwidth	1 GHz
Frequency Range	DC-500 MHz

Note To operate the device in complex baseband mode, configure each channel with identical ranges and termination. Complex baseband mode requires two input signals that are 90° out of phase.

Internal Frequency Reference

Initial adjustment accuracy	±200 × 10
Temperature stability	±1 × 10, maximum
Aging	±1 × 10 per year, maximum
Accuracy	**Initial adjustment accuracy** ± **Aging** ± **Temperature stability**

I/Q Input

I/Q Input Common-Mode Accuracy

Table 1. I/Q Input Common-Mode Accuracy, Typical

Common-Mode (V)	Accuracy (mV) at 23 °C
-0.25 to 1.50	±2.5
Conditions: Measured with a DMM. Common-mode offset is not adjusted during self-calibration. Valid for vertical ranges between 0.1 V_{pp} and 2.0 V_{pp}, differential. Measured with both input terminals terminated to ground through a high impedance >1 MΩ.	

I/Q Input DC Offset

Table 2. I/Q Input Differential DC Offset Error, Typical

Reference Location	DC Offset at 23 °C ± 5 °C
At ADC	<-57 dBFS
At connector	<10 mV
Conditions: Terminated with 100 Ω differential impedance.	

I/Q Input Absolute AC Gain Accuracy

Table 3. I/Q Input Absolute AC Gain Accuracy (dB)

Input Vertical Range (V_{pp}, Differential)	23 °C ± 5 °C	0 °C to 45 °C
0.5 to 4.0	±0.57	±0.71
	±0.15, typical	±0.28, typical
1.0 to 4.0	±0.44	±0.57
Conditions: Valid for all common-mode voltages. Measured with 10 MHz CW tone from a 100 Ω differential source.		

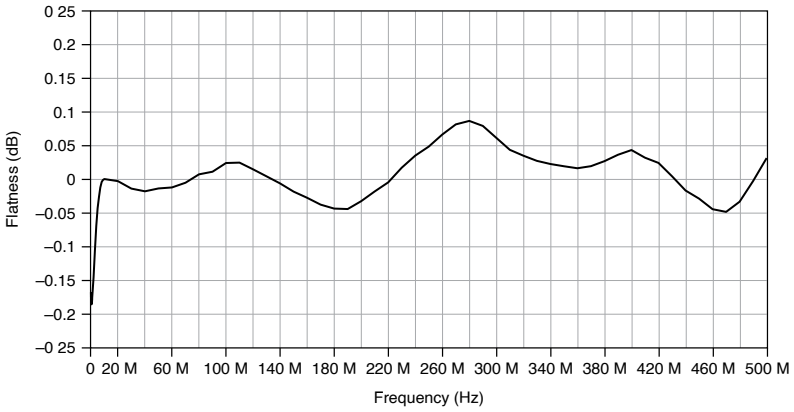
Input Vertical Range (V_{pp}, Differential)	23 °C ± 5 °C	0 °C to 45 °C
This specification is valid only when the module is operating within the specified ambient temperature range and within ±5 °C from the last self-calibration temperature, as indicated by the niRFSA Device Temperature property or NIRFSA_ATTR_DEVICE_TEMPERATURE attribute.		

I/Q Input Frequency Response

Table 4. I/Q Input Frequency Response (dB)

Frequency	Input Vertical Range (V_{pp}, Differential)	23 °C ± 5 °C	0 °C to 45 °C
100 kHz to 100 MHz	0.5 to 4.0	±0.31, typical	±0.36, typical
		±0.82	±0.92
	1.0 to 4.0	±0.67	±0.77
100 kHz to 250 MHz	0.5 to 4.0	±0.31, typical	±0.36, typical
		±0.82	±0.97
	1.0 to 4.0	±0.67	±0.83
100 kHz to 500 MHz	0.5 to 4.0	±0.31, typical	±0.62, typical
		±0.82	±1.22
	1.0 to 4.0	±0.68	±1.10
10 MHz to 250 MHz	0.5 to 4.0	±0.10, typical	±0.28, typical
10 MHz to 500 MHz		±0.25, typical	±0.62, typical
Conditions: Valid for all common-mode voltages. Referenced to 10 MHz. This specification is the individual I or Q channel flatness and is valid only when the module is operating within the specified ambient temperature range and within ±5 °C from the last self-calibration temperature, as indicated by the niRFSA Device Temperature property or the NIRFSA_ATTR_DEVICE_TEMPERATURE attribute.			

Figure 2. I/Q Input Frequency Response, Nominal



I/Q Input Settling Time

Table 5. I/Q Input Amplitude Settling Times, Nominal

Proximity to Final Settled Value (dB)	Settling Time (µs)
0.5	9
0.1	100
0.05	100
0.01	100
Nominal common-mode voltage settling time (0.01 dB)	1.2 ms

I/Q Input Average Noise Density

Table 6. I/Q Average Input Noise Density, Typical

Input Vertical Range (V_{pp}, Differential)	dBm/Hz	dBFs/Hz
0.5	-152	-149
1	-143	-146
2	-141	-149
3	-140	-150

Input Vertical Range (V_{pp}, Differential)	dBm/Hz	dBFs/Hz
Conditions: Terminated with a 100 Ω differential impedance.		

Figure 3. Input Average Noise Density vs. Linear Frequency (dBFS/Hz), Nominal

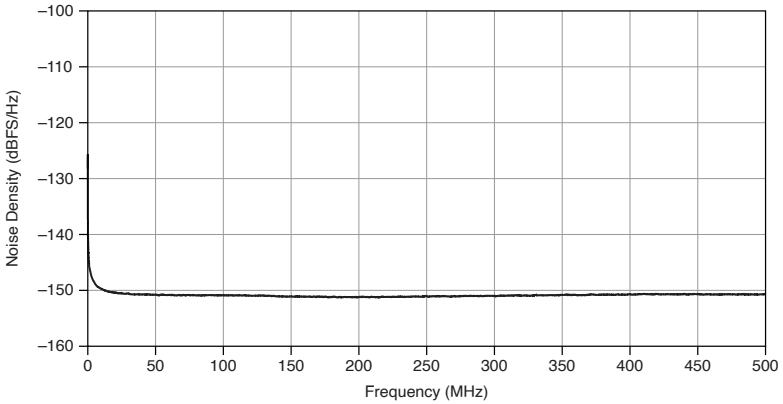
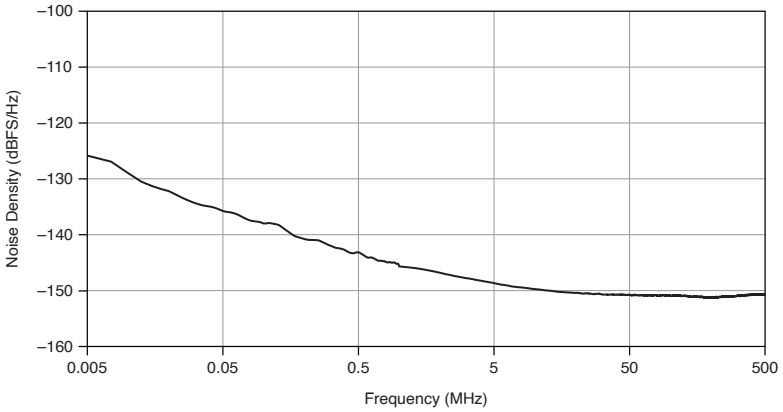


Figure 4. Input Average Noise Density vs. Log Frequency (dBFS/Hz), Nominal



I/Q Input Spectral Characteristics

Harmonics

Table 7. I/Q Input I Channel Highest Harmonic Spur Level (dBc)

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-74	-78	-76	-80
1	-75	-80	-76	-83

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
2	-76	-81	-73	-80
3	-78	-80	-73	-79

Table 8. I/Q Input Q Channel Highest Harmonic Spur Level (dBc)

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-78	-81	-78	-81
1	-80	-85	-82	-86
2	-79	-82	-80	-85
3	-77	-80	-79	-84

Table 9. I/Q Input I Channel THD (dBc)

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-74	-77	-75	-79
1	-75	-80	-75	-82
2	-76	-80	-73	-79
3	-77	-79	-73	-79

Table 10. I/Q Input Q Channel THD (dBc)

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-76	-79	-77	-81
1	-80	-84	-81	-85
2	-79	-81	-79	-84
3	-76	-79	-78	-83

Table 11. I/Q Input Second Harmonic (dBc), Nominal

Input Vertical Range (V_{pp}, Differential)	10 MHz	100 MHz
0.5	-89	-89
1	-89	-88
2	-89	-89
3	-89	-88

Table 12. I/Q Input Third Harmonic (dBc), Nominal

Input Vertical Range (V_{pp}, Differential)	10 MHz	100 MHz
0.5	-88	-91
1	-89	-89
2	-86	-85
3	-86	-84

Nonharmonics

Table 13. I/Q Input Nonharmonics (dBc)

Input Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-80	-82	-79	-81
1	-79	-81	-79	-81
2	-80	-81	-79	-81
3	-80	-81	-80	-82

I/Q Output

I/Q Output Common-Mode Accuracy

Table 14. I/Q Output Common-Mode Accuracy, Typical

Common-Mode (V)	Accuracy (mV) at 23 °C
-0.25 to 1.50	±2
Conditions: Measured with a DMM. Common-mode offset is not adjusted during self-calibration. Valid for vertical ranges between 0.1 V_{pp} and 2.0 V_{pp}, differential. Measured with both output terminals terminated to ground through a high impedance >1 MΩ.	

I/Q Output DC Offset

Table 15. I/Q Output Differential DC Offset Error (dBr), Typical

Temperature Range	I/Q Output DC Offset Error
23 °C ± 5 °C	-60
dBr is dB relative to the peak to peak output voltage setting (V_{pp}, differential).	

I/Q Output Absolute AC Gain Accuracy

Table 16. I/Q Output Absolute AC Gain Accuracy (dB)

Output Vertical Range (V_{pp}, Differential)	23 °C ± 5 °C	0 °C ± 45 °C
0.25 to 2.0	±0.43	±0.68
	±0.10, typical	±0.35, typical
Conditions: Valid for all common-mode voltages. 10 MHz CW tone into a 100 Ω differential load. This specification is valid only when the module is operating within the specified ambient temperature range and within ±5 °C from the last self-calibration temperature, as indicated by the niRFSG Device Temperature property or the NIRFSA_ATTR_DEVICE_TEMPERATURE attribute.		

I/Q Output Frequency Response

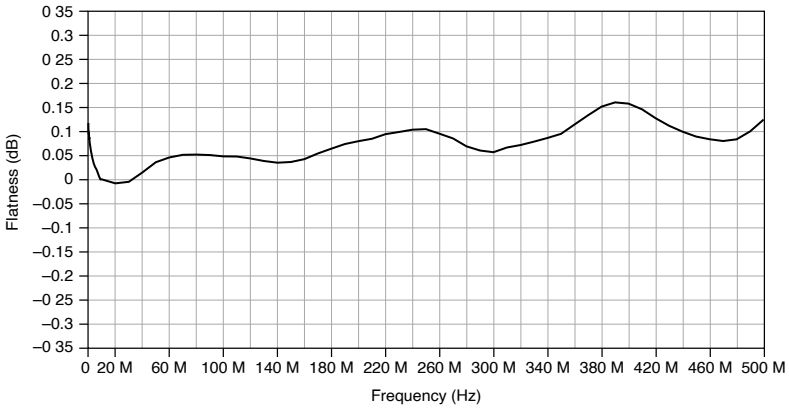
Table 17. I/Q Output Frequency Response (dB)

Frequency Range	Output Vertical Range (V_{pp}, Differential)	23 °C ± 5 °C	0 °C to 45 °C
100 kHz to 100 MHz	0.25 to 2.0	±0.17, typical	±0.24, typical
		±0.51	±0.61
	0.50 to 2.0	±0.44	±0.54
100 kHz to 250 MHz	0.25 to 2.0	±0.17, typical	±0.25, typical
		±0.57	±0.69
	0.50 to 2.0	±0.55	±0.68
100 kHz to 500 MHz	0.25 to 2.0	±0.18, typical	±0.36, typical
		±0.65	±0.83
	0.50 to 2.0	±0.59	±0.80

Conditions: Valid for all common-mode voltages. Referenced to 10 MHz.

This specification is the individual I or Q channel flatness and is valid only when the module is operating within the specified ambient temperature range and within ±5 °C from the last self-calibration temperature, as indicated by the niRFSG Device Temperature property or the NIRFSA_ATTR_DEVICE_TEMPERATURE attribute.

Figure 5. I/Q Output Frequency Response, Nominal



I/Q Output Settling Time

Table 18. I/Q Output Nominal Amplitude Settling Times

Proximity to Final Settled Value (dB)	Settling Time (us)
0.5	9
0.1	100
0.05	100
0.01	100
Nominal common-mode settling time (0.01 dB)	1.2 ms

I/Q Output Average Noise Density

Table 19. I/Q Average Output Noise Density, Typical

Output Vertical Range (V_{pp}, Differential)	dBm/Hz	dBFS/Hz
0.5	-152	-147
1	-154	-155
2	-156	-162
Conditions: Terminated with a 100 Ω differential impedance.		

I/Q Output Spectral Characteristics

Harmonics

Table 20. I/Q Output I or Q Channel Highest Harmonic Spur Level (dBc)

Output Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-77	-80	-70	-74
1	-78	-80	-69	-74
2	-69	-71	-66	-68

Table 21. I/Q Output I or Q Channel THD (dBc)

Output Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-75	-78	-69	-73
1	-77	-78	-69	-73
2	-69	-70	-65	-67

Table 22. I/Q Output I or Q Channel Second Harmonic (dBc)

Output Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-72	-82	-67	-77
1	-73	-81	-68	-77
2	-74	-82	-66	-76

Table 23. I/Q Output I or Q Channel Third Harmonic (dBc)

Output Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-73	-81	-69	-78
1	-79	-85	-73	-80
2	-72	-75	-65	-71

Nonharmonics

Table 24. I/Q Loopback Nonharmonics

Output Vertical Range (V_{pp}, Differential)	10 MHz		100 MHz	
	Typical	Nominal	Typical	Nominal
0.5	-76	-77	-75	-77
1	-79	-81	-79	-81
2	-80	-82	-79	-81

Additional Performance Information

Image Suppression

Table 25. I/Q Loopback Image Suppression (dBc), Nominal

Complex Bandwidth	Image Suppression
200 MHz	-69
1 GHz	-61
Image suppression is equivalent to or better than the specification at all frequency offsets within the specified bandwidth.	

SINAD and ENOB

Table 26. Input SINAD and ENOB

Real Bandwidth (MHz)	Real SINAD	Real ENOB	Complex SINAD	Complex ENOB
0.5	80.1	13.0	80.5	13.1
1	79.9	13.0	80.4	13.1
2.5	79.7	13.0	80.3	13.1
5	78.8	12.8	79.4	12.9
10	77.9	12.6	78.4	12.7
20	77.7	12.6	78.3	12.7
100	76.3	12.4	77.4	12.6
500	69.5	11.3	70.6	11.4
Complex equalized bandwidth is the combined bandwidth of I and Q channels.				

Table 27. Output SINAD and ENOB

Real Bandwidth (MHz)	Real SINAD	Real ENOB	Complex SINAD	Complex ENOB
0.5	79.3	12.9	80.5	13.1
1	78.7	12.8	80.1	13.0
2.5	75.8	12.3	77.9	12.6

Real Bandwidth (MHz)	Real SINAD	Real ENOB	Complex SINAD	Complex ENOB
5	76.8	12.5	78.7	12.8
10	75.8	12.3	77.9	12.6
20	74.3	12.0	76.8	12.5
100	69.7	11.3	72.5	11.8
500	63.6	10.3	66.6	10.8
Complex equalized bandwidth is the combined bandwidth of I and Q channels.				

I/Q Loopback Third-Order Intermodulation (IMD3)

Table 28. I/Q Loopback IMD3 (dBc), Typical

Vertical Range (V_{pp}, Differential)	0 °C to 45 °C	
	Center Frequency (MHz)	
	10 MHz	100 MHz
0.25	-77	-77
0.50	-77	-77
1.00	-78	-76
2.00	-73	-72
Conditions: Measured in loopback with two-tone stimulus, each tone is -8 dBFS with a 700 kHz spacing between the tones (equally spaced from the center frequency). IQ In and IQ Out ports are configured with the same Vertical Range and with 0 V common-mode.		

Figure 6. 10 MHz IMD3, Nominal

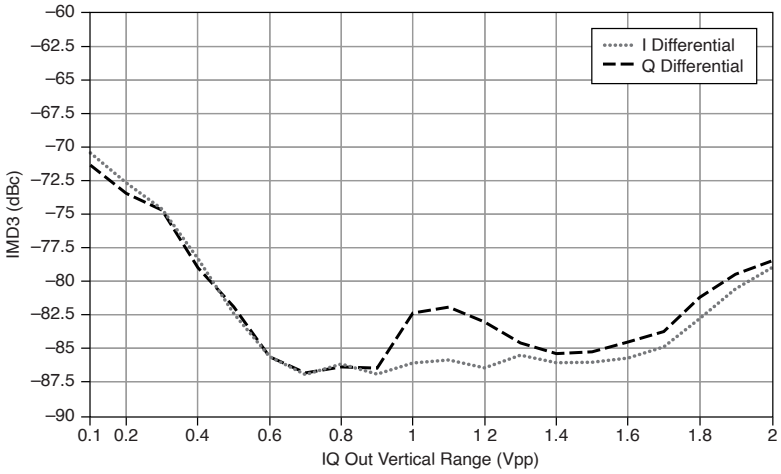
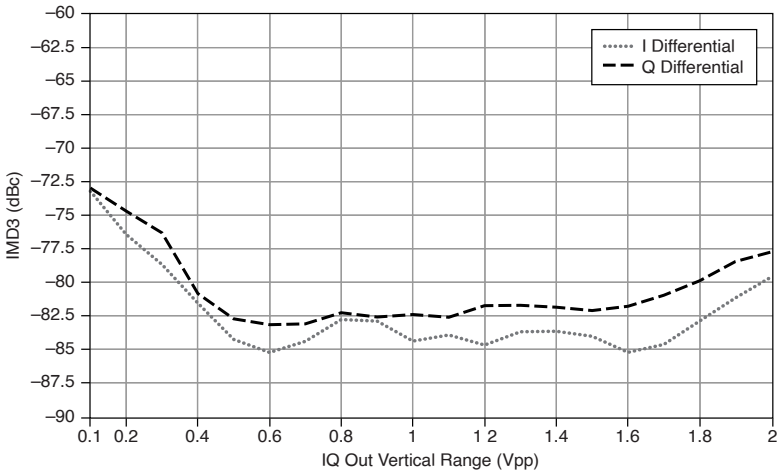


Figure 7. 100 MHz IMD3, Nominal



I/Q Loopback Second-Order Intermodulation (IMD2)

Table 29. I/Q Loopback IMD2 (dBc), Typical

Vertical Range (V_{pp}, Differential)	0 °C to 45 °C	
	Center Frequency (MHz)	
	10 MHz	100 MHz
0.25	-74	-68
0.50	-73	-67
1.00	-73	-68

Vertical Range (V_{pp}, Differential)	0 °C to 45 °C	
	Center Frequency (MHz)	
	10 MHz	100 MHz
2.00	-73	-67
Conditions: Measured in loopback with two-tone stimulus, each tone is -8 dBFS with a 700 kHz spacing between the tones (equally spaced from the center frequency). IQ In and IQ Out ports are configured with the same Vertical Range and with 0 V common-mode.		

Figure 8. 10 MHz IMD2, Nominal

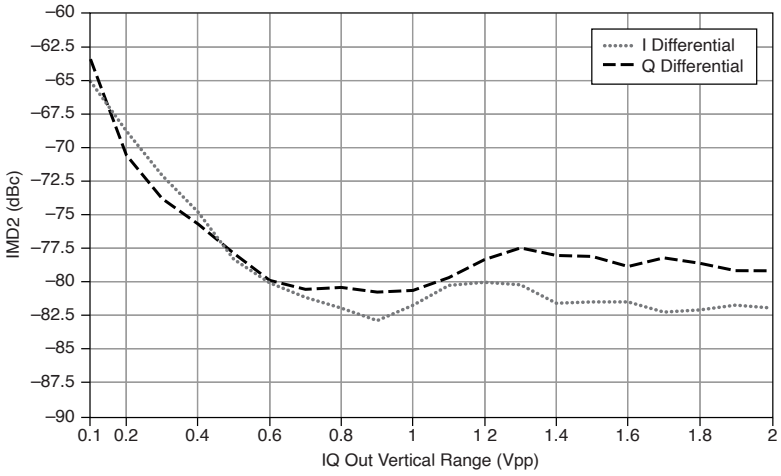
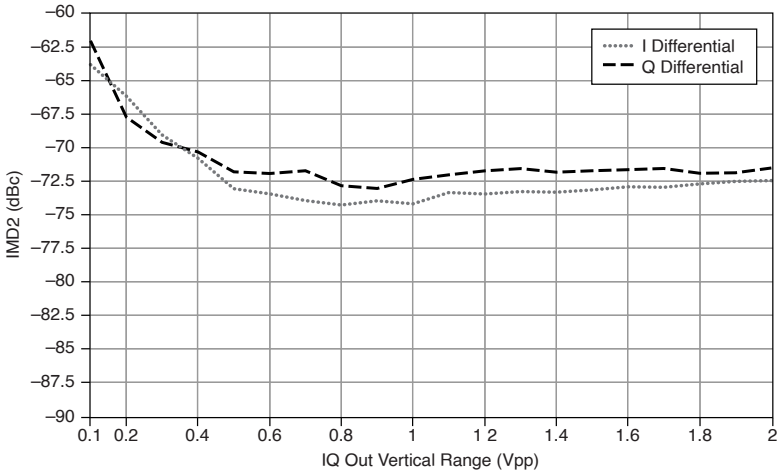


Figure 9. 100 MHz IMD2, Nominal

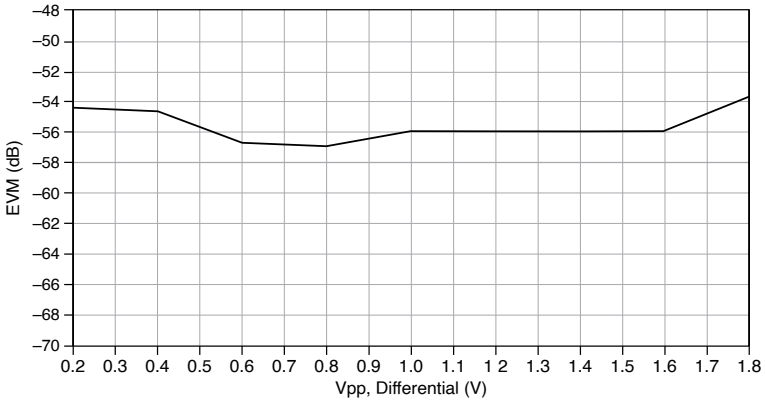


Application-Specific Modulation Quality

WLAN 802.11ax

EVM (Bandwidth: 80 MHz)	-50 dB, typical

Figure 10. 802.11ax Measured EVM (80 MHz)



WLAN 802.11ac

EVM (Bandwidth: 80 MHz)	-50 dB, typical
EVM (Bandwidth: 160 MHz)	-50 dB, typical

Figure 11. 802.11ac Measured EVM (80 MHz)

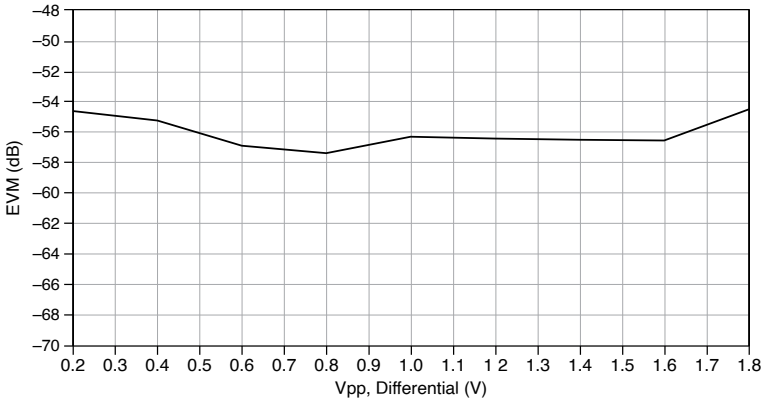
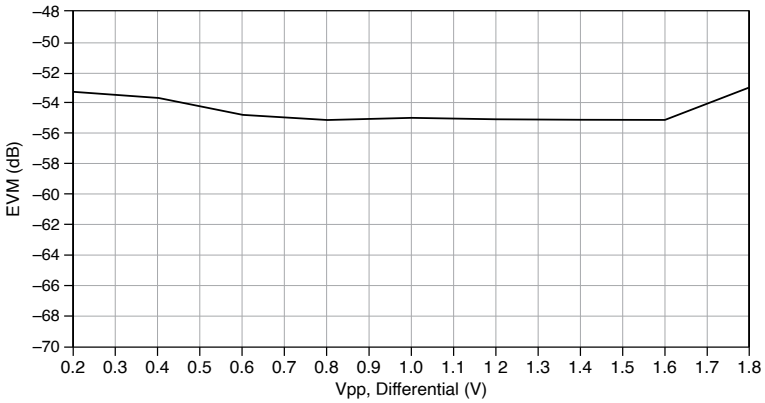


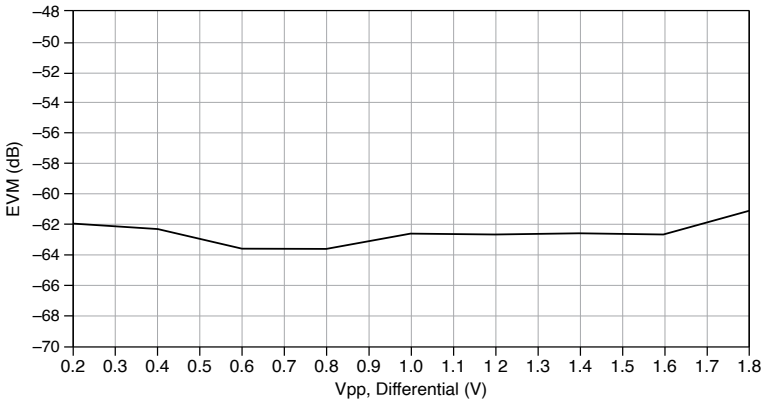
Figure 12. 802.11ac Measured EVM (160 MHz)



LTE

EVM (Bandwidth: 20 MHz)	-58 dB, typical

Figure 13. LTE Measured EVM (20 MHz)



Baseband Characteristics

Analog-to-digital converters (ADCs)	
I/Q data rate	19 kS/s to 1.25 GS/s
Digital-to-analog converters (DACs)	
I/Q data rate	19 kS/s to 1.25 GS/s

Onboard FPGA

FPGA	Xilinx Virtex-7 X690T
LUTs	433,200
Flip-flops	866,400
DSP48 slices	3,600
Embedded block RAM	52.9 Mbits
Data transfers	DMA, interrupts, programmed I/O
Number of DMA channels	56

Onboard DRAM

Memory size	2 banks, 2 GB per bank
Theoretical maximum data rate	12 GB/s per bank

Onboard SRAM

Memory size	2 MB
Maximum data rate (read)	31 MB/s
Maximum data rate (write)	29 MB/s

Front Panel I/O

I/Q IN 0

Connectors	MMPX (female)
Input coupling, per terminal	DC
Input type	Differential
Number of channels	2

Vertical Range

Input voltage range per I/Q input pin (no damage)	-3 V to 5 V
Common-mode range	-0.25 V to 1.5 V
Maximum vertical range	4 V_{pp}, differential

Impedance

DC differential input impedance	100 ± 10 Ω, typical

Figure 14. I/Q Input Impedance, Nominal

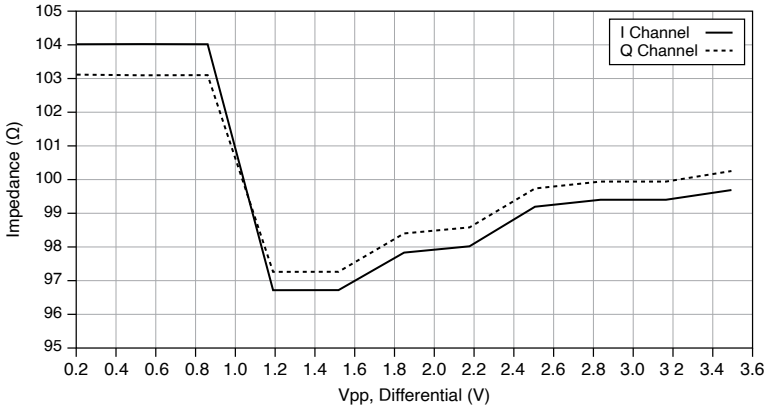
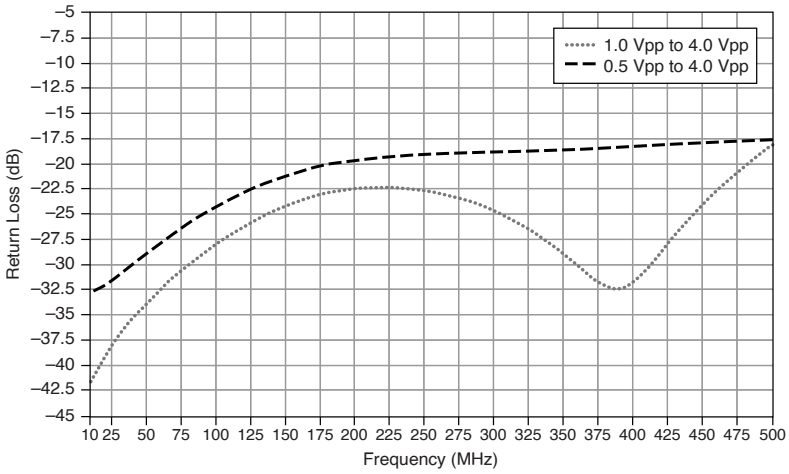


Figure 15. I/Q Input Differential Return Loss, Nominal



I/Q OUT 0

Connectors	MMPX (female)
Output coupling, per terminal	DC
Output type	differential
Number of channels	2

Vertical Range

Maximum voltage range per I/Q output pin (no damage)	V_{com} ±3.5 V
Common-mode range	-0.25 V to 1.5 V

Table 30. I/Q Output Vertical Range (V_{pp}, Differential)

NI-RFSG Signal Bandwidth Setting (Complex)	Maximum Vertical Range
≤ 160 MHz	3.4, nominal
≤ 1 GHz	2, typical
Conditions: Into a 100 Ω differential load.	

Impedance

DC differential output impedance	100 ± 10 Ω, typical

Figure 16. I/Q Output Impedance, Nominal

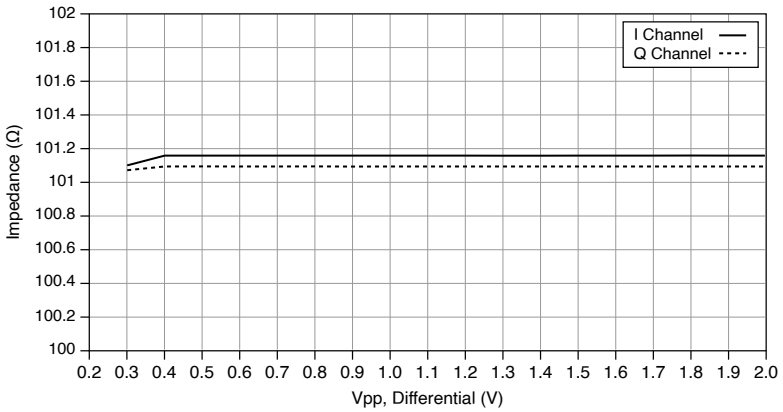
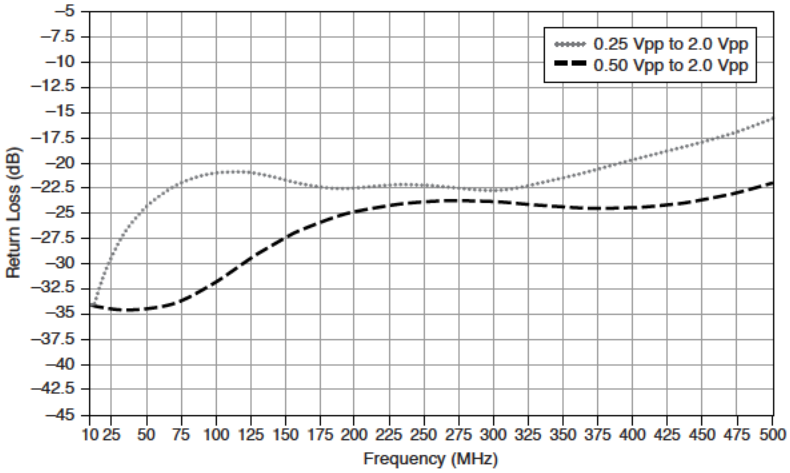


Figure 17. I/Q Output Differential Return Loss, Nominal



REF IN

Note **Frequency Accuracy** = **Tolerance** × **Reference Frequency**

Connector	MMPX (female)
Frequency	10 MHz
Tolerance	±10 × 10
Amplitude	0.7 V_{pk-pk} to 3.3 V_{pk-pk} into 50 Ω, typical.
Input impedance	50 Ω, nominal
Coupling	AC

Note Jitter performance improves with increased slew rate of input signal.

REF OUT

Connector	MMPX (female)
Frequency	10 MHz, nominal
Amplitude	1.65 V_{pk-pk} into 50 Ω, nominal
Output impedance	50 Ω, nominal
Coupling	AC

PFI 0

Connector	MMPX (female)
Input impedance	10 kΩ, nominal
Output impedance	50 Ω, nominal
Maximum DC drive strength	24 mA

Note Voltage levels are guaranteed by design through the digital buffer specifications.

Table 31. Voltage Levels

Absolute maximum input range	-0.5 V to 5.5 V
V_{IL}, maximum	0.8 V
V_{IH}, minimum	2.0 V
V_{OL}, maximum	0.2 V with 100 µA load
V_{OH}, minimum	2.9 V with 100 µA load

DIGITAL I/O

Connector	Molex Nano-Pitch I/O
5.0 V Power	±5%, 50 mA maximum, nominal

Table 32. DIGITAL I/O Signal Characteristics

Signal	Type	Direction
MGT Tx± <3..0>	Xilinx Virtex-7 GTH	Output
MGT Rx± <3..0>	Xilinx Virtex-7 GTH	Input
MGT REF±	Differential	Input
DIO <1..0>	Single-ended	Bidirectional
DIO <7..2>	Single-ended	Bidirectional
5.0 V	DC	Output
GND	Ground	—

Note DIO <1..0> pins are multiplexed with MGT REF±.

Digital I/O High Speed Serial MGT

Note For detailed FPGA and High Speed Serial Link specifications, refer to Xilinx documentation.

Data rate	500 Mbps to 12 Gbps, nominal
Number of Tx channels	4
Number of Rx channels	4
I/O AC coupling capacitor	100 nF

MGT Tx± <3..0> Channels

Minimum differential output voltage	800 mV_{pk-pk} into 100 Ω, nominal

Conditions: transmitter output swing at maximum setting.

MGT Rx± <3..0> Channels

Table 33. Differential Input Voltage Range

≤6.6 GB/s	150 mV_{pk-pk} to 2,000 mV_{pk-pk}, nominal
>6.6 GB/s	150 mV_{pk-pk} to 1,250 mV_{pk-pk}, nominal
Differential input resistance	100 Ω, nominal

MGT Reference Clock

Note Internal MGT Reference is derived from the Sample Clock PLL. Available frequencies are 2.5 GHz / N, where 4 ≤ N ≤ 32. Set via MGT component level IP (CLIP).

Table 34. Clocking Resources

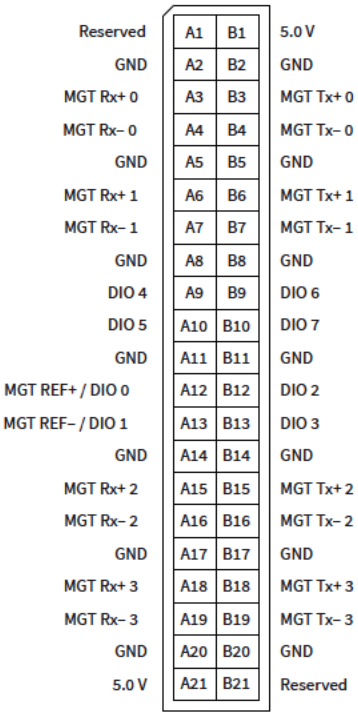
Data Clock	156.25 MHz
MGT REF± Input	60 MHz to 820 MHz, nominal

MGT REF± Input

AC coupling capacitors	100 nF
Differential input resistance	100 Ω, nominal
Differential input V_{pk-pk} range	350 mV to 2000 mV, nominal
Absolute maximum input range	-1.25 V to 4.5 V

Note Absolute maximum levels measured at input, prior to AC coupling capacitors.

Figure 18. DIGITAL I/O Nano-Pitch Connector



Power Requirements

Table 35. Power Requirements

Voltage (V_{DC})	Typical Current (A)
+3.3	3.3
+12	6.0
Power is 83 W, typical. Consumption is from both PXI Express backplane power connectors. Conditions: Simultaneous generation and acquisition using NI-RFSG and NI-RFSA at 1.25 GS/s I/Q rate, 45 °C ambient temperature. Power consumption depends on FPGA image being used.	

Calibration

Interval	1 year

Physical Characteristics

PXIe-5820 module	3U, two slot, PXI Express module 4.1 cm × 13.0 cm × 21.6 cm 1.6 in. × 5.1 in. × 8.5 in.
Weight	795 g (28.0 oz)

Environment

Maximum altitude	2,000 m (800 mbar) (at 25 °C ambient temperature)
Pollution Degree	2

Indoor use only.

Operating Environment

Ambient temperature range	0 °C to 45 °C
Relative humidity range	10% to 90%, noncondensing

Storage Environment

Ambient temperature range	-40 °C to 71 °C
Relative humidity range	5% to 95%, noncondensing

Shock and Vibration

Operating shock	30 g peak, half-sine, 11 ms pulse
Random vibration	
Operating	5 Hz to 500 Hz, 0.3 g_{rms}
Nonoperating	5 Hz to 500 Hz, 2.4 g_{rms}

Compliance and Certifications

Safety Compliance Standards

This product is designed to meet the requirements of the following electrical equipment safety standards for measurement, control, and laboratory use:

- IEC 61010-1, EN 61010-1
- UL 61010-1, CSA C22.2 No. 61010-1

Note For safety certifications, refer to the product label or the Product Certifications and Declarations section.

Electromagnetic Compatibility

This product meets the requirements of the following EMC standards for electrical equipment for measurement, control, and laboratory use:

- EN 61326-1 (IEC 61326-1): Class A emissions; Basic immunity
- EN 55011 (CISPR 11): Group 1, Class A emissions
- AS/NZS CISPR 11: Group 1, Class A emissions
- FCC 47 CFR Part 15B: Class A emissions
- ICES-001: Class A emissions

Note In the United States (per FCC 47 CFR), Class A equipment is intended for use in commercial, light-industrial, and heavy-industrial locations. In Europe, Canada, Australia, and New Zealand (per CISPR 11), Class A equipment is intended for use only in heavy-industrial locations.

Note Group 1 equipment (per CISPR 11) is any industrial, scientific, or medical equipment that does not intentionally generate radio frequency energy for the treatment of material or inspection/analysis purposes.

Note For EMC declarations, certifications, and additional information, refer to the Product Certifications and Declarations section.

Product Certifications and Declarations

Refer to the product Declaration of Conformity (DoC) for additional regulatory compliance information. To obtain product certifications and the DoC for NI products, visit ni.com/product-certifications, search by model number, and click the appropriate link.

Environmental Management

NI is committed to designing and manufacturing products in an environmentally responsible manner. NI recognizes that eliminating certain hazardous substances from our products is beneficial to the environment and to NI customers.

For additional environmental information, refer to the **Engineering a Healthy Planet** web page at ni.com/environment. This page contains the environmental regulations and directives with which NI complies, as well as other environmental information not included in this document.

EU and UK Customers

- **Waste Electrical and Electronic Equipment (WEEE)**—At the end of the product life cycle, all NI products must be disposed of according to local laws and regulations. For more information about how to recycle NI products in your region, visit ni.com/environment/weee.

电子信息产品污染控制管理办法（中国 RoHS）

- **中国 RoHS**— NI 符合中国电子信息产品中限制使用某些有害物质指令(RoHS)。关于 NI 中国 RoHS 合规性信息，请登录 ni.com/environment/rohs_china。(For information about China RoHS compliance, go to ni.com/environment/rohs_china.)